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IN THE SPECIFICATION:

Please substitute the attached specification for the originally filed one.

A noise reduction filter array ~~ARRAY TYPE NOISE REDUCTION~~
FILTER

BACKGROUND OF THE INVENTION

5 Field of the Invention

The present invention relates generally to a noise reduction filter array~~array type noise reduction filters~~, and more particularly to ~~an~~A noise reduction filter array~~array type noise reduction filter~~, in which each inductance portions
10 is~~are~~ each formed of two coil portions, and winding directions of the coil portions are set to be different so as to offset mutual interference, thus minimizing the generation of electromagnetic interference.

15 Description of the Prior Art

Generally, when electronic devices are operated, electromagnetic wave noises such as various types of power noises or clock pulse source noises exist within the devices. Especially, in mobile communication terminals, as power
20 frequency becomes higher, great electromagnetic wave noise is generated.

Such electromagnetic wave noises are mutually propagated between circuits along circuit power lines or signal lines within electronic devices, thus causing incorrect operation of
25 each device. Further, power noise or clock pulse source noise

generated within an electronic device set is propagated to another electronic device set along a power supply line of the device set, thus causing interference with a normal operation of another electronic device set. On the other hand, a
5 corresponding electronic device set can interfere with its normal operation due to noise propagated from another device. The interference phenomenon due to such electromagnetic wave noises is so called Electro-Magnetic Interference (EMI).

Therefore, for the purpose of performing normal operation
10 of electronic devices, methods for reducing the electromagnetic wave noises must be considered in order to prevent this EMI when the devices are designed. Generally, a method for inserting a noise reduction filter between each circuit and each circuit power source of the electronic
15 devices, or between each circuit and each clock pulse source of the electronic devices is used as a method for reducing the electromagnetic wave noises.

Recently, a noise reduction filter array ~~an array type~~
~~noise reduction filter~~ has been popularized as a commonly used
20 noise reduction filter. The noise reduction filter array
~~array type noise reduction filter~~ is constructed in an array
type such that a single chip has a plurality of noise
reduction filters within it.

Fig. 1a is a schematic sectional view showing a
25 conventional A noise reduction filter array ~~array type noise~~

~~reduction filter 10.~~ Referring to Fig. 1a, the noise
reduction filter array ~~the array type noise reduction filter~~
10 comprises two noise reduction filters 10a and 10b. The
noise reduction filters 10a and 10b each has ~~have~~ first and
5 second ground electrode layers 12 and 13, capacitance portions
14a and 15a or 14b and 15b, and an inductance portion 17a or
17b. The first and second ground electrode layers 12 and 13
are respectively arranged at the upper and lower portions of a
chip 11. The capacitance portions 14a and 15a or 14b and 15b
10 are formed inside each of the first and second ground
electrode layers 12 and 13. The inductance portion 17a or 17b
is formed in a coil pattern. The first and second ground
electrode layers 12 and 13 function as common electrodes
shared between the noise reduction filters 10a and 10b.
15 Further, input and output ports (not shown) of each noise
reduction filter are formed on the front and back surfaces of
the chip 11. The input ports formed on the front surface of
the chip 11 are each connected to one end of each of the
inductance portions 17a and 17b, and the capacitance portions
20 14a and 15a, while the output ports formed on the back surface
of the chip 11 are each connected to the other end of each of
the inductance portions 17a and 17b, and the capacitance
portions 14b and 15b.

In the ~~array structure of the noise reduction filter~~
25 array ~~array type noise reduction filter 10,~~ the first and

second inductance portions 17a and 17b are symmetrically arranged adjacently to each other at the center portion of the chip 11, thus causing inductance coupling due to mutual inductance. In other words, crosstalk which is mutual electromagnetic interference can occur between the noise reduction filters 10a and 10b. Consequently, the noise reduction filter array ~~array type noise reduction filter~~ is problematic in that undesirable influence is generated between the filters 10a and 10b due to the mutual interference, thus causing the incorrect operation of each noise reduction filter.

Fig. 1b is a graphic view showing the electromagnetic interference characteristics of a conventional noise reduction filter array ~~array type noise reduction filter~~. Referring to Fig. 1b, a full line represents characteristics of each noise reduction filter in the noise reduction filter array ~~array type noise reduction filter~~, and a dotted line represents the electromagnetic interference characteristics generated between the noise reduction filters. As shown with the dotted line, in the conventional noise reduction filter array ~~array type noise reduction filter~~, crosstalk occurs largely between the noise reduction filters. This is due to the mutual inductance generated between the filters arranged within a single chip, as described above. Therefore, such mutual inductance causes electromagnetic interference between the filters, thus

deteriorating the filter characteristics of the array type noise reduction filter.

As described above, in this noise reduction filter technical field, a new noise reduction filter array ~~array type~~
5 ~~noise reduction filter~~ has been required for effectively preventing crosstalk from occurring due to the mutual inductance between the inductance portions of respective noise reduction filters.

SUMMARY OF THE INVENTION

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Accordingly, the present invention has been made keeping in mind the above problems occurring in the prior art, and an object of the present invention is to provide an noise reduction filter array ~~array type noise reduction filter~~, in
15 which each inductance portions ~~is~~ are each formed of as a plurality of coils, and winding directions of some of the coils are set opposite each other, so as to offset mutual interference generated between the coils of the noise reduction filters due to mutual inductance, thus minimizing
20 electromagnetic interference.

In accordance with one aspect of the present invention, the above and other objects can be accomplished by the provision of noise reduction filter array having a plurality of filters horizontally arranged within a single chip, each
25 filter comprising, two inductance portions comprised of first

and second coils connected vertically in the chip, a ground portion arranged over or under the inductance portion, and a capacitance portion arranged over or under the ground portion, wherein the first coil of one inductance portion is
5 constructed to be wound in the same direction as that of the first coil of the other adjacent inductance portion, and the second coil of the one inductance portion is constructed to be wound in a direction opposite to the second coil of the other adjacent inductance portion.

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~~an array type noise reduction filter, comprising a plurality of noise reduction filters horizontally arranged within a single chip, each comprising, an inductance portion comprised of first and second coils approximately vertically
15 connected in the chip, a ground portion arranged over or under the inductance portion, and a capacitance portion arranged over or under the ground portion; wherein a second coil of any inductance portion is constructed to be wound in a direction opposite to a second coil of another adjacent inductance
20 portion.~~

According to a preferred embodiment of this invention, inductance values of the first and second coils are set to be approximately the same value, such that mutual inductance generated by adjacent coils wound in opposite directions can
25 be effectively offset.

According to another embodiment of this invention, the ground portion can be comprised of a first ground portion arranged over the inductance portion and a second ground portion under the inductance portion. In this case, preferably the capacitance portion is comprised of a first capacitance portion arranged under the first ground portion and a second capacitance portion arranged over the second ground portion.

According to still another preferred embodiment of this invention, the ground portion is arranged at one position of upper and lower portions of the chip, and the capacitance portion is comprised of a first capacitance portion arranged over the ground portion and a second capacitance portion arranged under the ground portion to be opposite the first capacitance portion, such that each noise reduction filter is formed in the shape of pi (π).

On the other hand, the ground portion is formed of a single layer shared between a plurality of noise reduction filters, such that it is provided as a common ground electrode for a plurality of noise reduction filters.

According to the most preferred embodiment of this invention, each noise reduction filter further comprises an isolation means formed between the first and second coils to isolate the first and second coils from undesirable electromagnetic influence between the first and second coils.

Preferably, such an isolation means can be a conductor layer having a via hole for connecting the first coil to the second coil.

In accordance with another aspect of the present
5 invention, there is provided a noise reduction filter array
having a plurality of filters horizontally arranged within a
single chip, each filter comprising, two inductance portions,
each comprised of first and second coil connected vertically
within the chip, and each arranged horizontally, a ground
10 portion arranged at at least one position over or under the
inductance portions according to the arrangement direction of
the inductance portions, a plurality of capacitance portions
each vertically arranged over or under the ground portion in
approximately the same direction as that of each of the
15 inductance portions, and an isolation means for blocking
electromagnetic influence between the first and the second
coil of each of the inductance portions, wherein the first
coil of one inductance portion is constructed to be wound in
the same direction as that of the first coil of the other
20 adjacent inductance portion, and the second coil of the one
inductance portion is constructed to be wound in a direction
opposite to the second coil of the other adjacent inductance
portion .an array type noise reduction filter having a single
chip shape, comprising a plurality of inductance portions each
25 comprised of first and second coils approximately vertically

~~connected within a chip, and arranged horizontally to each
other; a ground portion arranged at at least one position over
or under the inductance portions according to the arrangement
direction of a plurality of inductance portions; and a
5 plurality of capacitance portions each vertically arranged
over or under the ground portion in approximately the same
direction as that of each of a plurality of inductance
portions, wherein the inductance portions each include
isolation means for blocking electromagnetic influence between
10 first and second coils of each of the inductance portions, and
a second coil of any inductance portion is constructed to be
wound in a direction opposite to a second coil of another
adjacent inductance portion.~~

BRIEF DESCRIPTION OF THE DRAWINGS

The above and other objects, features and other advantages of the present invention will be more clearly understood from the following detailed description taken in conjunction with the accompanying drawings, in which:

Fig. 1a is a schematic sectional view showing a conventional noise reduction filter array~~array type noise reduction filter~~;

10 Fig. 1b is a graphic view showing the electromagnetic interference characteristics of the conventional—noise reduction filter array~~array type noise reduction filter~~;

Fig. 2 is a schematic perspective view showing a noise reduction filter array~~an array type noise reduction filter~~ having two noise reduction filters according to a preferred embodiment of this invention;

Fig. 3a is a circuit diagram of a noise reduction filter array~~an array type noise reduction filter~~ having four noise reduction filters according to a preferred embodiment of this invention;

20 Figs. 3b and 3c are graphic views showing the characteristics of each of the noise reduction filters of Fig. 3a; and

Fig. 4 is a schematic sectional view showing another noise reduction filter array~~array type noise reduction filter~~

having four noise reduction filters according to another preferred embodiment of this invention.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

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Fig. 2 is a schematic perspective view showing a noise reduction filter array ~~an array type noise reduction filter-20~~ according to a preferred embodiment of this invention. Referring to Fig. 2, the noise reduction filter array ~~array type noise reduction filter-20~~ comprises two noise reduction filters 20a and 20b within a single chip 21. The noise reduction filters 20a and 20b are each comprised of first and second ground electrodes 22 and 23, a first capacitance portion 24a or 24b, a second capacitance portion 25a or 25b, and an inductance portion. One end of the first capacitance portion 24a or 24b is connected to the first ground portion 22, and the other end thereof is connected to input ports (not shown). Further, one end of the second capacitance portion 25a or 25b is connected to the second ground portion 23, and the other end thereof is connected to output ports (not shown). One end of the inductance portion is connected to the input ports and the other end thereof is connected to the output ports. Especially, in the present invention, the inductance portion is comprised of a first coil 27a' or 27b' and a second coil 27a'' or 27b''. Further, a conductor layer

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29a or 29b is provided as an electromagnetic isolation means between the first coil 27a' or 27b' and the second coil 27a" or 27b".

As shown in Fig. 2, each inductance portion is formed of
5 first and second coils 27a' and 27a", or 27b' and 27b"
vertically connected. The first coil 27a' of one inductance
portion is formed in the same winding direction as that of the
first coil 27b' of the other inductance portion. However, the
second coil 27a" is formed in a winding direction opposite to
10 that of the second coil 27b" of the other inductance portion.
Therefore, mutual inductance having a polarity opposite to the
mutual inductance induced between the first coils 27a' and
27b' is induced between the second coils 27a" and 27b". In
such a structure, mutual inductances having opposite
15 polarities are generated between the first and second coils,
such that the mutual inductances can offset each other. Here,
it is preferable to arrange each of first and second coils of
one inductance portion on approximately the same plane as each
of the first and second coils of the other inductance portion.
20 Further, it is preferable to set the first and second coils to
have the same inductance value L_a when the same voltage is
applied. This perfectly offsets mutual inductance M induced
between the first coils and mutual inductance $-M$ induced
between the second coils, thus entirely minimizing
25 electromagnetic interference.

However, the present invention is characterized in that electromagnetic interference is reduced through an offset operation between mutual inductances having opposite polarities by forming the inductance portions as two coils and
5 adjusting each direction of the coils. Therefore, even if each of the first and second coils of one inductance portion is not arranged on the same plane as that of the other inductance portion, or the first and second coils do not have the same inductance value, it probably belongs to the range of
10 the present invention that the direction of any one of the first and second coils is set differently from the other to minimize electromagnetic interference. Further, in the preferred embodiment of this invention, the first and second ground portions 22 and 23 are each formed as a common
15 electrode for two noise reduction filters. However, the ground portions 22 and 23 can each be divided into two ground electrodes for respective noise reduction filters.

Further, in the preferred embodiment of this invention, conductor layers as isolation means for isolating the first
20 and second coils from electromagnetic influence are formed. In other words, the conductor layers serve to prevent inductance values due to mutual influence between the first and second coils from varying. Preferably, plate-shaped conductor layers each having a via hole for connecting the
25 first and second coils to each other can be used as conduction

layers for blocking the mutual electromagnetic influence while connecting the first coil to the second coil. The isolation means such as the conduction layers are described below in detail.

5 Fig. 3a is a circuit diagram of an array type noise reduction filter having four noise reduction filters according to a preferred embodiment of this invention. In Fig. 3a, capacitance portions and ground portions are omitted so as to conveniently describe functions of the inductance portions of
10 the filters and the conductor layers included in the inductance portions.

Referring to Fig. 3a, inductance portions of four noise reduction filters ²30a, ²30b, ²30c and ²30d are each formed to be separated into first and second coils (inductance La of Fig.
15 3a). In the case that inductance portions are each formed to be separated into two coils just as the inductance portions adapted to the present invention, it is difficult to exactly adjust total inductance value of the two coils. In other words, provided that the inductance value of each of the first
20 and second coils is La, if two coils are formed in the same winding direction, the total inductance value of the two coils becomes larger than 2La, while if two coils are formed in opposite winding directions, its total inductance value becomes smaller than 2La. Thereby, it is difficult to
25 previously set the total inductance value as the same value

required by the inductance portions of the four noise reduction filters. Consequently, a problem in that it is difficult to design the noise reduction filters by exactly predicting the characteristics of each of the noise reduction
5 filters is caused.

Therefore, the conductor layer 29 for preventing the mutual electromagnetic influence between two coils is formed between the first and second coils, such that the variation of the total inductance value due to the interaction of the two
10 coils can be prevented. As a result, each inductance portion can be embodied to have the same inductance value. Further, if inductance portions are each required to employ another desired inductance value, the total inductance value can be easily adjusted by selecting each inductance value of the
15 first and second coils.

Figs. 3b and 3c are graphic views showing the characteristics of each of the noise reduction filters. Fig. 3b shows the characteristics of the first and third noise reduction filters, and Fig. 3c shows the characteristics of
20 the second and fourth noise reduction filters. In the first and third noise reduction filters, the second coil of each inductance portion has the same winding direction as that of the first coil. In the second and fourth noise reduction filters, the second coil of each inductance portion has a
25 winding direction opposite to that of the first coil.

In this case, in the first and third noise reduction filters, typically the total inductance value of the first and second coils of each inductance portion may be larger than the sum of the inductance values of the first and second coils, while in the second and fourth noise reduction filters, the total inductance value of the first and second coils of each inductance portion may be smaller than the sum of the inductance values of the first and second coils. However, in the preferred embodiment of this invention, the conductor layer for blocking the electromagnetic influence between the first and second coils is formed, such that each total inductance value for all inductance portions has almost the same value as the sum of the inductance values of the two coils. Therefore, as shown in Figs. 3b and 3c, the noise reduction filters, in which the winding direction of the second coil is opposite to the first coil, have approximately the same low pass characteristics.

Fig. 4 is a schematic sectional view showing another array type noise reduction filter 40 having four noise reduction filters 40a, 40b, 40c and 40d according to another preferred embodiment of this invention. Referring to Fig. 4, in the array type noise reduction filter 40, a ground electrode 42 and first and second capacitance portions 44 and 45 can be concentrically formed at the lower portion of a chip 41. Further, the ground electrode 42 can be formed as a

common electrode shared between the four noise reduction filters 40a, 40b, 40c and 40d. As described above, the ground electrode 42 is formed as one electrode, thus saving one ground electrode in comparison with the embodiment using two ground electrodes as shown in Fig. 2. Accordingly, the embodiment of Fig. 4 is advantageous in that it can simplify the manufacturing process of the array type noise reduction filter, in addition to reducing its manufacturing costs. The preferred embodiment of this invention can be similarly adapted such that the ground electrode 42 and the capacitance portions 44 and 45 are concentrically formed at the upper portion of the chip 41.

As shown in Fig. 4, pi-shaped noise reduction filters in which the capacitance portions 44 and 45 are respectively arranged over and under the ground electrode 42 can be modified by omitting one of the capacitance portions 44 and 45. In such a structure, preferably the capacitance portion is connected to one of the input and output ports of each noise reduction filter so as to realize the same characteristics.

In other words, it is preferable to embody the noise reduction filters each employing one capacitance portion in the manufacturing process, because the input ports or output ports connected to the capacitance portion are arranged to the same position when each capacitance portion is arranged at

only one position over or under the ground electrode.

As described above, the present invention provides an array type noise reduction filter, which inductance portions of noise reduction filters are each formed of first and second
5 coils, and the winding directions of some of the coils are set opposite each other, such that mutual interference generated between the coils of the noise reduction filters due to mutual inductance can be offset. Further, the present invention is advantageous in that mutual electromagnetic interference can
10 be minimized by forming conductor layers between first and second coils to block mutual influence between the coils, and required filter characteristics can be designed by realizing exact inductance values.

Although the preferred embodiments of the present
15 invention have been disclosed for illustrative purposes, those skilled in the art will appreciate that various modifications, additions and substitutions are possible, without departing from the scope and spirit of the invention as disclosed in the accompanying claims.

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